

## FEATURES

- Plastic package has underwrites laboratory Flammability Classification 94V-0
- Glass passivated chip junction
- Built-in strain relief,
- Suoer Fast switching speed for high efficiency
- High temperature soldering guaranteed: 260 °C/10 seconds

## MECHANICAL DATA

Case: JEDED DO-214AB transfer molded plastic

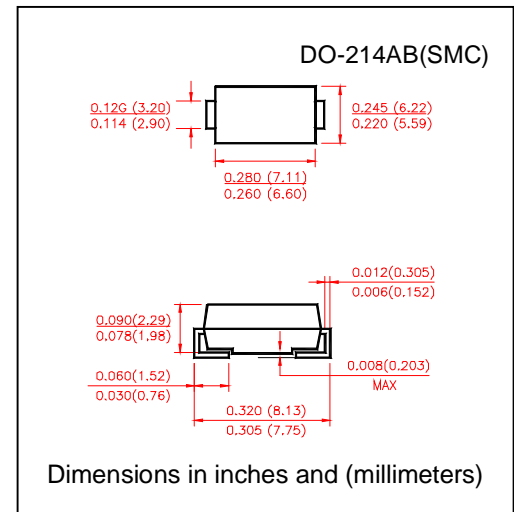
- Terminals: Solder plated, solderable per MIL-STD-750
- Method 2026
- Polarity: Color band denotes cathode end
- Weight: 0.007 ounce, 0.25 gram

**VOLTAGE RANGE**

**50 to 600 Volts**

**CURRENT**

**3.0 Ampere**



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified.
- Single phase, half wave, 60Hz, resistive or inductive load.
- For capacitive load derate current by 20%.

	SYMBOLS	ES3AC	ES3BC	ES3CC	ES3DC	ES3EC	ES3GC	ES3JC	UNIT
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	600	Volts
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	420	Volts
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	600	Volts
Maximum Average Forward Rectified Current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	3.0							Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	100							Amps
Maximum Instantaneous Forward Voltage @ 3.0A	$V_F$	0.95			1.25	1.7			Volts
Maximum DC Reverse Current at rated DC Blocking Voltage per element	$T_A = 25^\circ\text{C}$	5.0							$\mu\text{A}$
	$T_A = 125^\circ\text{C}$	300							
Typical Reverse Recovery Time Test conditions $I_F=0.5\text{A}$ , $I_R=1.0\text{A}$ , $I_{RR}=0.25\text{A}$	$t_{rr}$	35							nS
Typical Junction Capacitance (Measured at 1.0MHz and applied reverse voltage of 4.0V)	$C_J$	45				30			pF
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	55							$^\circ\text{C}/\text{W}$
	$R_{\theta JL}$	17							
Operating Junction Temperature Range	$T_J$	(-55 to +150)							$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	(-55 to +150)							$^\circ\text{C}$

### Notes:

1. Thermal resistance from Junction to ambient and from junction to lead mounted on P.C.B. with 0.3"×0.3"(8.0mm × 8.0mm) copper pad areas.

## RATING AND CHARACTERISTIC CURVES ES3AC THRU ES3JC

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

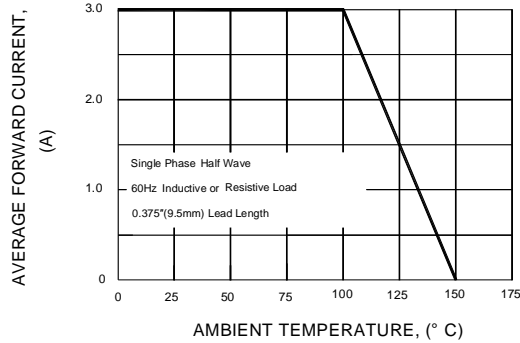


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

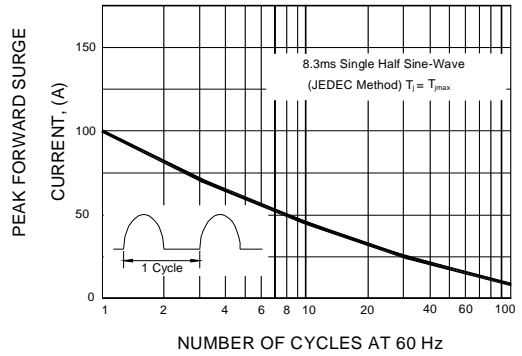


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

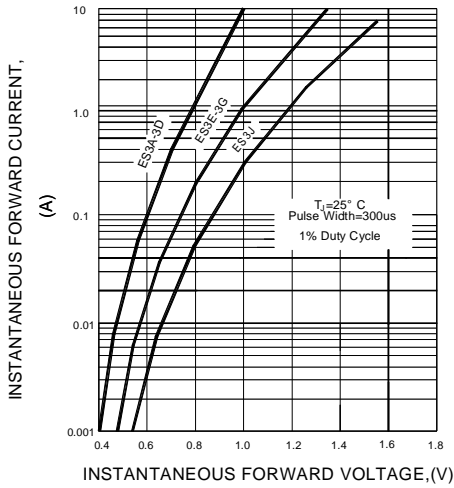


FIG.4-TYPICAL REVERSE CHARACTERISTICS

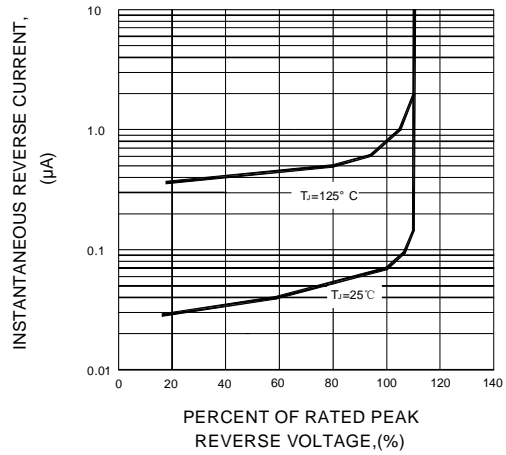


FIG.5-TYPICAL JUNCTION CAPACITANCE

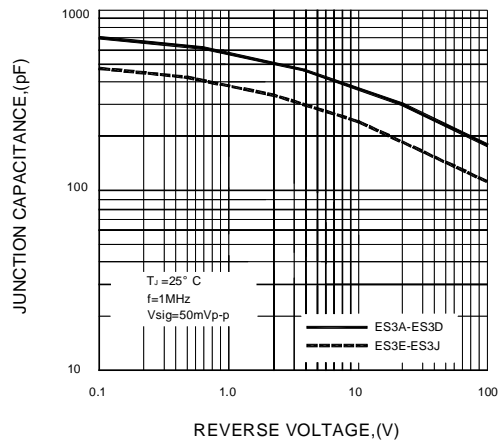
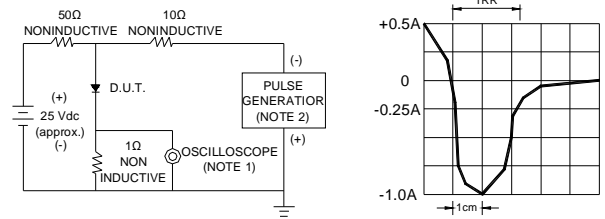


FIG.6-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



- NOTES : 1. Rise Time=7ns max. Input Impedance= 1 megohm. 22pF  
2. Rise time=10ns max. Source Impedance= 50 ohms

SET TIME BASE FOR 50/100ns/cm